

## Refine Search

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### Search Results -

Terms	Documents
L2 and (undoped silicon or USG)and (doped near5 silicon) and (expos\$ near5 (doped silicon or BPSG or PSG))	46

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**Database:**

- US Pre-Grant Publication Full-Text Database
- US Patents Full-Text Database
- US OCR Full-Text Database
- EPO Abstracts Database
- JPO Abstracts Database
- Derwent World Patents Index
- IBM Technical Disclosure Bulletins

**Search:**

Refine Search

Recall Text
Clear
Interrupt

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### Search History

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**DATE:** Thursday, October 14, 2004    [Printable Copy](#)    [Create Case](#)

<u>Set</u> <u>Name</u> <u>Query</u>	<u>Hit</u> <u>Count</u>	<u>Set</u> <u>Name</u>
side by side		result set
<i>DB=PGPB,USPT,USOC,EPAB,JPAB,DWPI,TDBD; PLUR=YES; OP=ADJ</i>		
<u>L5</u> L2 and (undoped silicon or USG)and (doped near5 silicon) and (expos\$ near5 (doped silicon or BPSG or PSG))	46	<u>L5</u>
<u>L4</u> L3 and planar\$	26	<u>L4</u>
<u>L3</u> L2 and (undoped silicon or USG)and (doped near5 silicon) and third layer	37	<u>L3</u>
<u>L2</u> L1	22187	<u>L2</u>
<i>DB=USPT; PLUR=YES; OP=ADJ</i>		
<u>L1</u> (438/624-787).ccls.	22187	<u>L1</u>

END OF SEARCH HISTORY